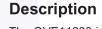


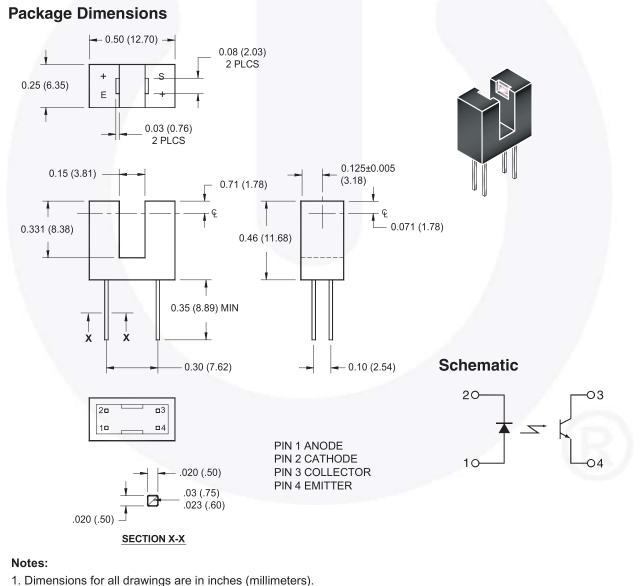
QVE11233 Slotted Optical Switch

Features

- Lead spacing 0.300"
- Gap width of 0.150"
- Printed circuit board mounting
- 2mm aperture width



The QVE11233 is designed to allow the user maximum flexibility in applications. Each switch consists of an infrared emitting diode facing an NPN phototransistor across a 0.150" (3.81mm) gap.



2. Tolerance of ± 0.010 (0.25) on all non-nominal dimensions unless otherwise specified.

Absolute Maximum Ratings (TA = 25°C unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating	Units
T _{OPR}	Operating Temperature	-40 to +85	°C
T _{STG}	Storage Temperature	-40 to +85	°C
T _{SOL-I}	Soldering Temperature (Iron) ⁽²⁾⁽³⁾⁽⁴⁾	240 for 5 sec	°C
T _{SOL-F}	Soldering Temperature (Flow) ⁽²⁾⁽⁴⁾	260 for 10 sec	°C
INPUT (EMIT	TER)		
I _F	Continuous Forward Current	50	mA
V _R	Reverse Voltage	6	V
PD	Power Dissipation ⁽¹⁾	100	mW
OUTPUT (SE	NSOR)		
V _{CEO}	Collector to Emitter Voltage	30	V
V _{ECO}	Emitter to Collector Voltage	4.5	V
I _C	Collector Current	20	mA
P _D	Power Dissipation ⁽¹⁾	150	mW

Notes:

1. Derate power dissipation linearly, on each component, 1.67mW/°C above 25°C.

2. RMA flux is recommended.

3. Methanol or isopropyl alcohols are recommended as cleaning agents.

4. Soldering iron tip 1/16" (1.6mm) from housing.

Electrical/Optical Characteristics (T_A = 25°C)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
INPUT (EMI	TTER)					
V _F	Forward Voltage	I _F = 20mA			1.7	V
I _R	Reverse Leakage Current	V _R = 2V			100	μA
OUTPUT (S	ENSOR)		-			
BV _{ECO}	Emitter to Collector Breakdown	I _E = 100μΑ, E _e = 0	5.0	5		V
BV _{CEO}	Collector to Emitter Breakdown	$I_{\rm C} = 1 {\rm mA}, {\rm E}_{\rm e} = 0$	30		1	V
I _{CEO}	Collector to Emitter Leakage	$V_{CE} = 10V, E_e = 0$			100	nA
COUPLED			1			
I _{C(ON)}	On-State Collector Current	I _F = 20mA, V _{CE} = 5V	0.5			mA
V _{CE (SAT)}	Saturation Voltage	$I_{\rm F} = 20$ mA, $I_{\rm C} = 0.25$ mA			0.40	V
	1	I				

				U		
TRADEMARKS The following includes register	red and unregistered trader	narks and service marks,	owned by Fairchild Semiconductor and/or its glob	al subsidiaries, and is not		
intended to be an exhaustive I	list of all such trademarks.		65: 7953 585	20		
2Cool™	F-PFS™		PowerTrench [®]	The Power Franchise [®]		
AccuPower™	FRFET®	SM	PowerXS™	b wer		
AX-CAP™*	Global Power Re	source	Programmable Active Droop™	p wer franchise		
BitSiC™	GreenBridge™		QFET [®] QS™	TinyBoost™		
Build it Now™	Green FPS™	a via a TM	Quiet Series™	TinyBuck™		
	Green FPS™ e-S G <i>m</i> ax™	enes	RapidConfigure™	TinyCalc™		
CorePOWER™	GTO™			TinyLogic®		
CROSSVOLT™ CTL™	IntelliMAX™			TINYOPTO™		
Current Transfer Logic™	ISOPLANAR™		Saving our world, 1mW/W/kW at a time™	TinyPower™		
DEUXPEED®		eakers Sound Louder	SignalWise™	TinyPWM™		
Dual Cool™	and Better		SmartMax™ SMART START™	TinyWire™ Trans Ciot™		
EcoSPARK®	MegaBuck™		SMART START™	TranSiC™		
EfficientMax™	MICROCOUPLE	₹™	Solutions for Your Success™ SPM [®]	TriFault Detect™ TRUECURRENT [®] *		
ESBC™	MicroFET™		STEALTH™	μSerDes™		
ESBC™ F [®]	MicroPak™		SuperFET®	μser Des ····		
To irabild [®]	MicroPak2™		SuperSOT™-3	SerDes		
Fairchild [®] Fairchild Semiconductor [®]	MillerDrive™		SuperSOT™-6	UHC [®]		
FACT Quiet Series™	MotionMax™		SuperSOT™-8	Ultra FRFET™		
FACT®	mWSaver™		SupreMOS®	UniFET™		
FAST®	OptoHiT™ OPTOLOGIC [®]		SyncFET™	VCX™		
FastvCore™	OPTOPLANAR®		Sync-Lock™	VisualMax™		
FETBench™	OFTOFLANAN			VoltagePlus™		
FlashWriter [®] * FPS™	CU.®		CONCERNE .	XS™		
* Trademarks of System Ge	eneral Corporation, used	under license by Fairchi	Id Semiconductor.			
DISCLAIMER						
RELIABILITY, FUNCTION, OF OR CIRCUIT DESCRIBED H	R DESIGN. FAIRCHILD DC EREIN; NEITHER DOES IT EXPAND THE TERMS OF	DES NOT ASSUME ANY CONVEY ANY LICENSE	WITHOUT FURTHER NOTICE TO ANY PRODU- LIABILITY ARISING OUT OF THE APPLICATION E UNDER ITS PATENT RIGHTS, NOR THE RIGH DE TERMS AND CONDITIONS, SPECIFICALLY	OR USE OF ANY PRODUCT ITS OF OTHERS. THESE		
LIFE SUPPORT POLICY						
			OMPONENTS IN LIFE SUPPORT DEVICES OR RATION.	SYSTEMS WITHOUT THE		
As used herein:						
life, and (c) whose accordance with instru	r systems are devices or implant into the body or failure to perform wh uctions for use provided o result in a significant inj	(b) support or sustain en properly used in in the labeling, can be	 A critical component in any component system whose failure to perform can cause the failure of the life support dev safety or effectiveness. 	be reasonably expected to		
ANTI-COUNTERFEITING	POLICY					
		g Policy. Fairchild's Anti-C	ounterfeiting Policy is also stated on our external w	vebsite, www.fairchildsemi.com,		
Counterfeiting of semiconduct parts. Customers who inadver applications, and increased co proliferation of counterfeit part Distributors who are listed by are genuine parts, have full tra and product information. Fairc Fairchild will not provide any w	rtently purchase counterfeit ost of production and manuf s. Fairchild strongly encour: country on our web page ci aceability, meet Fairchild's c aceability, meet Fairchild's c shild and our Authorized Dis varranty coverage or other a	parts experience many pl facturing delays. Fairchild ages customers to purcha ted above. Products custo uality standards for handl tributors will stand behind assistance for parts bough	ufacturers of semiconductor products are experier oblems such as loss of brand reputation, substan- is taking strong measures to protect ourselves and se Fairchild parts either directly from Fairchild or fir mers buy either from Fairchild directly or from Aut ing and storage and provide access to Fairchild's t all warranties and will appropriately address any v at from Unauthorized Sources. Fairchild is committ buying direct or from authorized distributors.	dard performance, failed d our customers from the om Authorized Fairchild horized Fairchild Distributors uil range of up-to-date technical varranty issues that may arise.		
PRODUCT STATUS DEFIN	NITIONS					
Definition of Terms						
Datasheet Identification	Product Status		Definition			
Advance Information	Formative / In Design	Datasheet contains the in any manner without	e design specifications for product development. Specifications may change			
Drolinsinon	First Dreduction		eliminary data; supplementary data will be pub	lished at a later date. Fairchild		

©2009 Fairchild Semiconductor Corporation QVE11233 Rev. 1.0.1

Preliminary

No Identification Needed

Obsolete

First Production

Full Production

Not In Production

Rev. 162

Semiconductor reserves the right to make changes at any time without notice to improve design. Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.

Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights or others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor hardles, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC